

TOSHIBA Field-Effect Transistor Silicon N / P Channel MOS Type

SSM6L39TU

○ Power Management Switch Applications

○ High-Speed Switching Applications

- N-ch: 1.5-V drive
P-ch: 1.8-V drive
- N-ch, P-ch, 2-in-1
- Low ON-resistance
 - Q1 N-ch: $R_{on} = 247 \text{ m}\Omega$ (max) (@ $V_{GS} = 1.5 \text{ V}$)
 $R_{on} = 190 \text{ m}\Omega$ (max) (@ $V_{GS} = 1.8 \text{ V}$)
 $R_{on} = 139 \text{ m}\Omega$ (max) (@ $V_{GS} = 2.5 \text{ V}$)
 - Q2 P-ch: $R_{on} = 430 \text{ m}\Omega$ (max) (@ $V_{GS} = -1.8 \text{ V}$)
 $R_{on} = 294 \text{ m}\Omega$ (max) (@ $V_{GS} = -2.5 \text{ V}$)

Q1 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	20	V
Gate-source voltage		V_{GSS}	± 10	V
Drain current	DC	I_D	1.6	A
	Pulse	I_{DP}	3.2	

Q2 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-20	V
Gate-source voltage		V_{GSS}	± 8	V
Drain current	DC	I_D	-1.5	A
	Pulse	I_{DP}	-3	

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$) (Q1, Q2 Common)

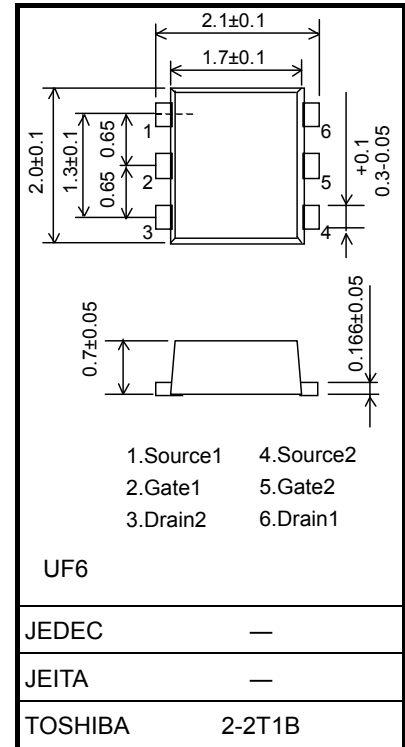
Characteristics	Symbol	Rating	Unit
Drain power dissipation	P_D (Note 1)	500	mW
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 to 150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

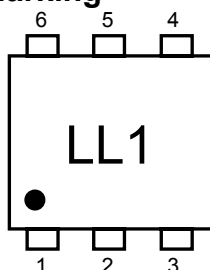
Note1: Mounted on an FR4 board. (total dissipation) (25.4 mm × 25.4 mm × 1.6 mm, Cu Pad : 645 mm²)

Unit: mm

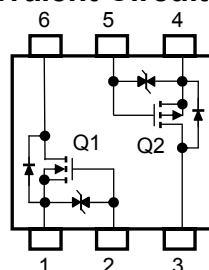


Weight: 7.0 mg (typ.)

Marking



Equivalent Circuit (top view)



Q1 Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	I _D = 1 mA, V _{GS} = 0 V	20	—	—	V
		V (BR) DSX	I _D = 1 mA, V _{GS} = -10 V	12	—	—	
Drain cutoff current		I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V	—	—	1	μA
Gate leakage current		I _{GSS}	V _{GS} = ±10 V, V _{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V _{th}	V _{DS} = 3 V, I _D = 1 mA	0.35	—	1.0	V
Forward transfer admittance		Y _{fs}	V _{DS} = 3 V, I _D = 1 A (Note 2)	2.5	5.0	—	S
Drain-source ON-resistance	R _{DS (ON)}		I _D = 1 A, V _{GS} = 4.0 V (Note 2)	—	87	119	mΩ
			I _D = 1 A, V _{GS} = 2.5 V (Note 2)	—	105	139	
			I _D = 0.8 A, V _{GS} = 1.8 V (Note 2)	—	125	190	
			I _D = 0.3 A, V _{GS} = 1.5 V (Note 2)	—	145	247	
Input capacitance		C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	—	260	—	pF
Output capacitance		C _{oss}		—	45	—	
Reverse transfer capacitance		C _{rss}		—	37	—	
Total Gate Charge		Q _g	V _{DS} = 10 V, I _D = 1.6 A V _{GS} = 4 V	—	7.5	—	nC
Gate-Source Charge		Q _{gs}		—	5.6	—	
Gate-Drain Charge		Q _{gd}		—	1.9	—	
Switching time	Turn-on time	t _{on}	V _{DD} = 10 V, I _D = 0.5 A	—	8.3	—	ns
	Turn-off time	t _{off}	V _{GS} = 0 to 2.5 V, R _G = 4.7 Ω	—	11.5	—	
Drain-source forward voltage		V _{DSF}	I _D = -1.6 A, V _{GS} = 0 V (Note 2)	—	-0.8	-1.2	V

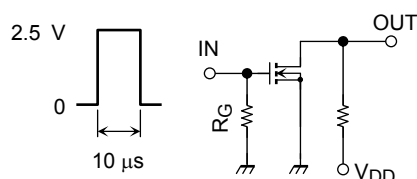
Q2 Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	I _D = -1 mA, V _{GS} = 0 V	-20	—	—	V
		V (BR) DSX	I _D = -1 mA, V _{GS} = +8 V	-12	—	—	
Drain cutoff current		I _{DSS}	V _{DS} = -20 V, V _{GS} = 0 V	—	—	-10	μA
Gate leakage current		I _{GSS}	V _{GS} = ±8 V, V _{DS} = 0 V	—	—	±1	μA
Gate threshold voltage		V _{th}	V _{DS} = -3 V, I _D = -1 mA	-0.3	—	-1.0	V
Forward transfer admittance		Y _{fs}	V _{DS} = -3 V, I _D = -1 A (Note 2)	1.6	3.2	—	S
Drain-source ON-resistance	R _{DS (ON)}		I _D = -1.0 A, V _{GS} = -4 V (Note 2)	—	160	213	mΩ
			I _D = -0.8 A, V _{GS} = -2.5 V (Note 2)	—	210	294	
			I _D = -0.1 A, V _{GS} = -1.8 V (Note 2)	—	280	430	
Input capacitance		C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	—	250	—	pF
Output capacitance		C _{oss}		—	43	—	
Reverse transfer capacitance		C _{rss}		—	35	—	
Total Gate Charge		Q _g	V _{DS} = -10 V, I _D = -1.5 A V _{GS} = -4 V	—	6.4	—	nC
Gate-Source Charge		Q _{gs}		—	4.5	—	
Gate-Drain Charge		Q _{gd}		—	1.9	—	
Switching time	Turn-on time	t _{on}	V _{DD} = -10 V, I _D = -1 A,	—	12	—	ns
	Turn-off time	t _{off}	V _{GS} = 0 to -2.5 V, R _G = 4.7 Ω	—	11.2	—	
Drain-source forward voltage		V _{DSF}	I _D = 1.5 A, V _{GS} = 0 V (Note 2)	—	0.88	1.2	V

Note 2: Pulse test

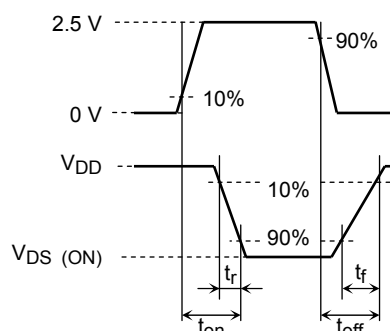
Q1 Switching Time Test Circuit

(a) Test Circuit

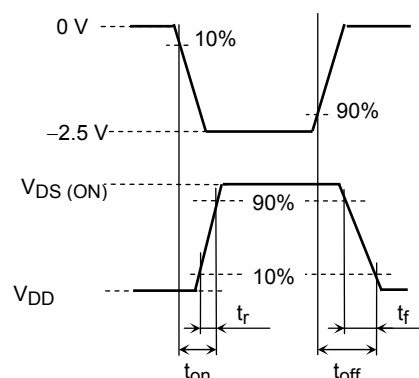


$V_{DD} = 10 \text{ V}$
 $R_G = 4.7 \text{ } \Omega$
 $D.U. \leq 1\%$
 $V_{IN}: t_r, t_f < 5 \text{ ns}$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}

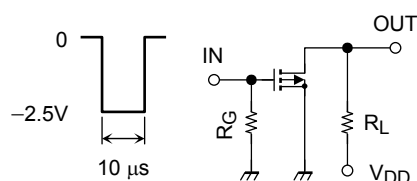


(c) V_{OUT}



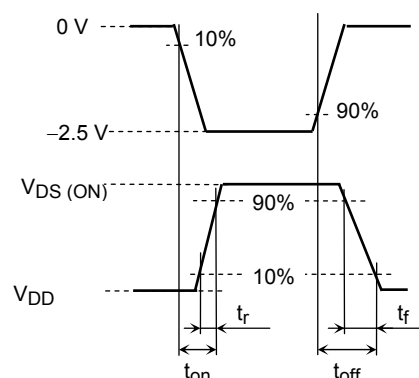
Q2 Switching Time Test Circuit

(a) Test Circuit



$V_{DD} = -10 \text{ V}$
 $R_G = 4.7 \text{ } \Omega$
 $D.U. \leq 1\%$
 $V_{IN}: t_r, t_f < 5 \text{ ns}$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}



(c) V_{OUT}

Q1 Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the Q1 of the SSM6L39TU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

Q2 Usage Considerations

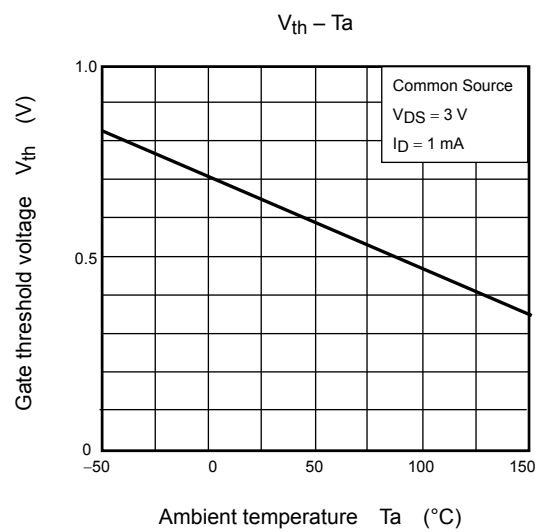
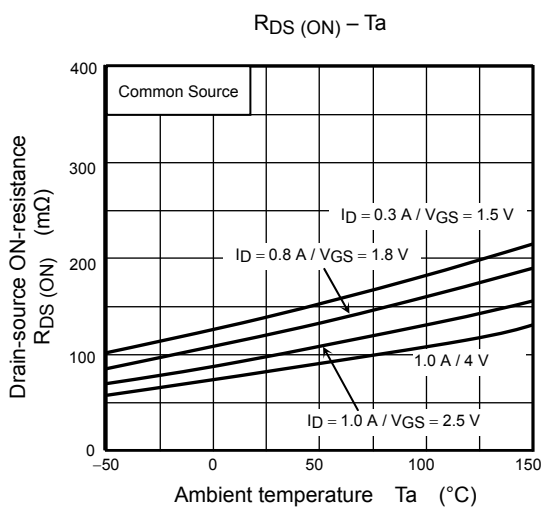
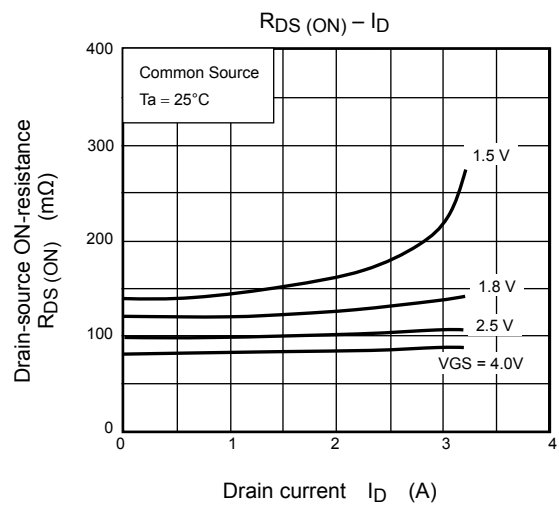
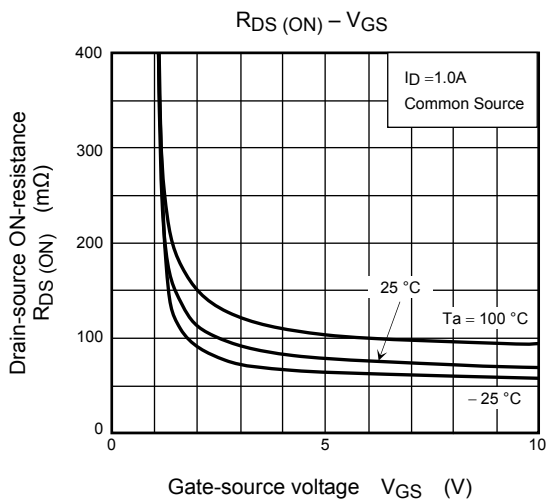
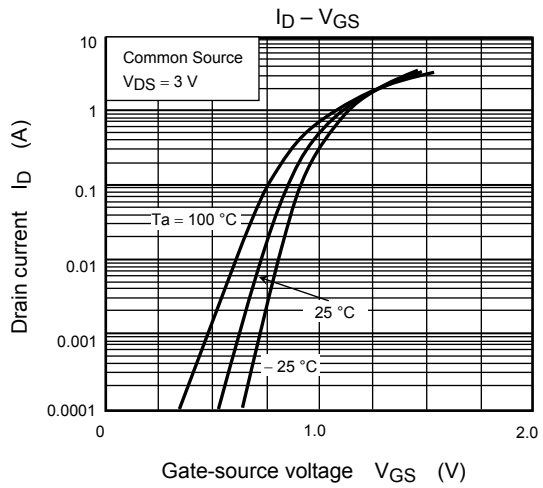
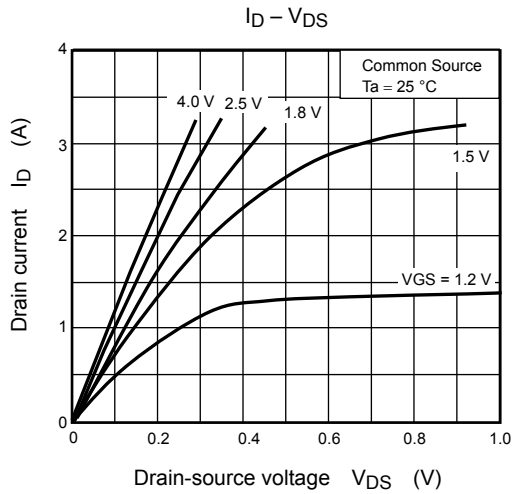
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (−1 mA for the Q2 of the SSM6L39TU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

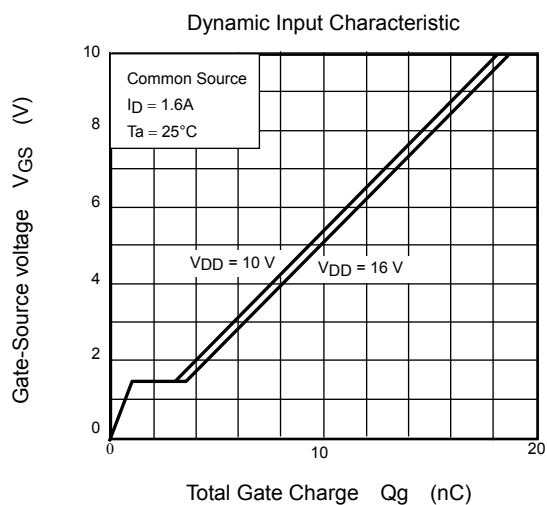
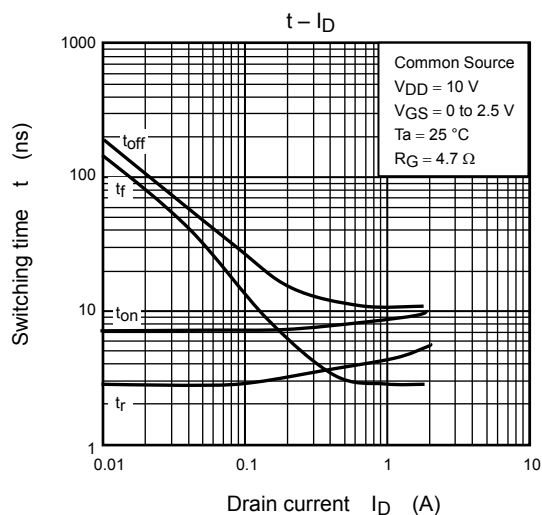
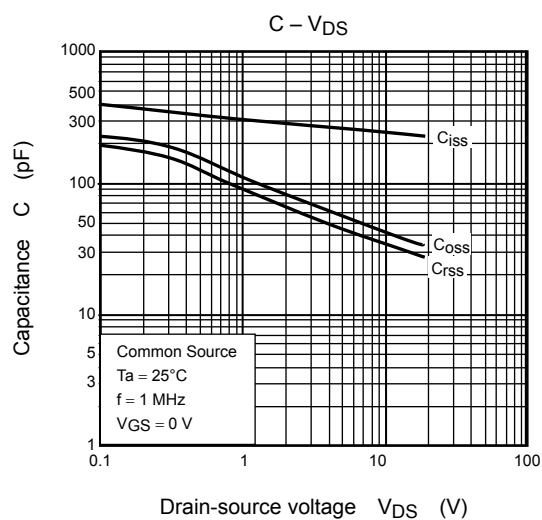
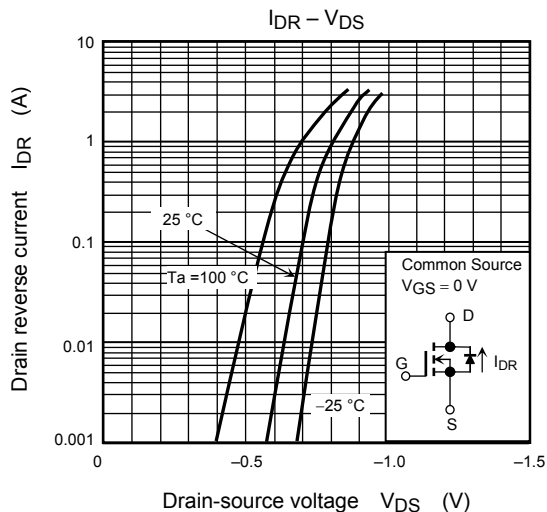
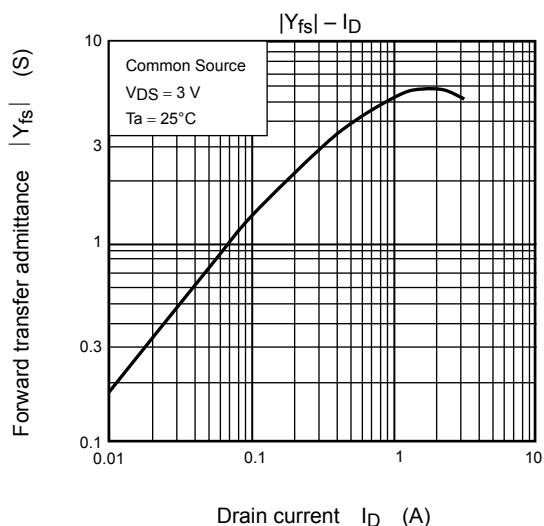
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

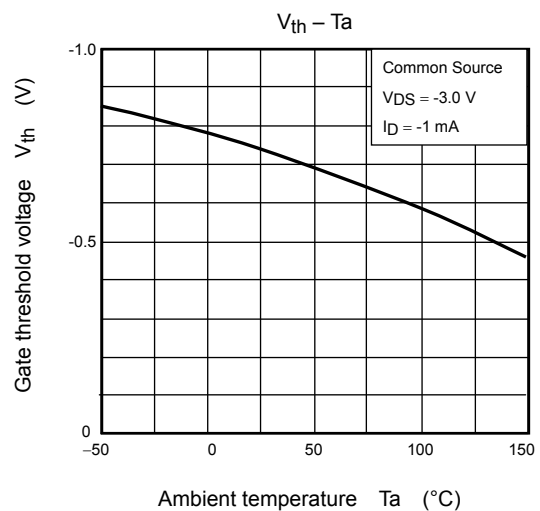
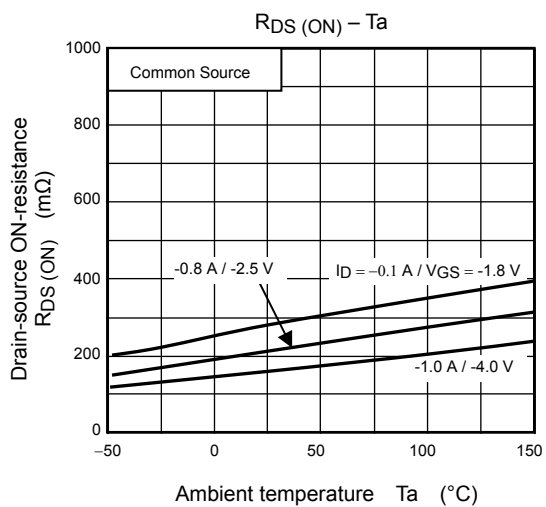
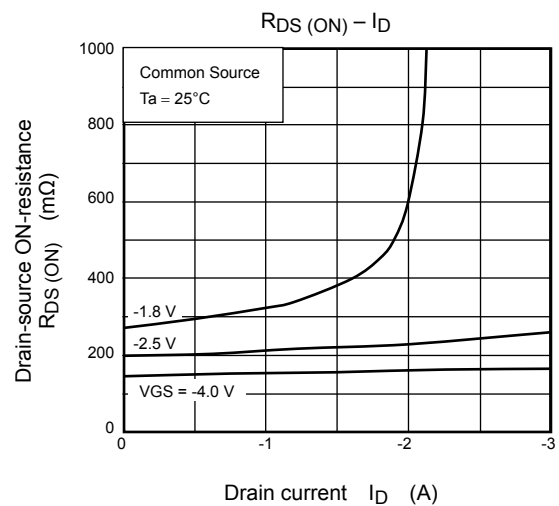
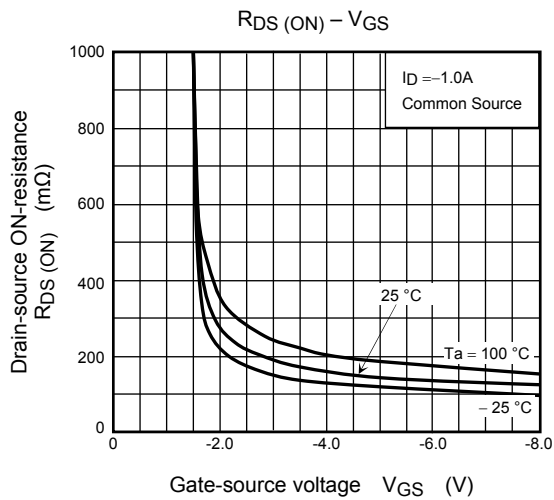
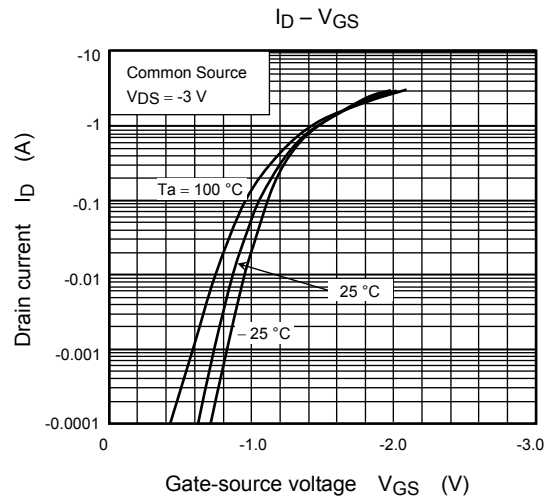
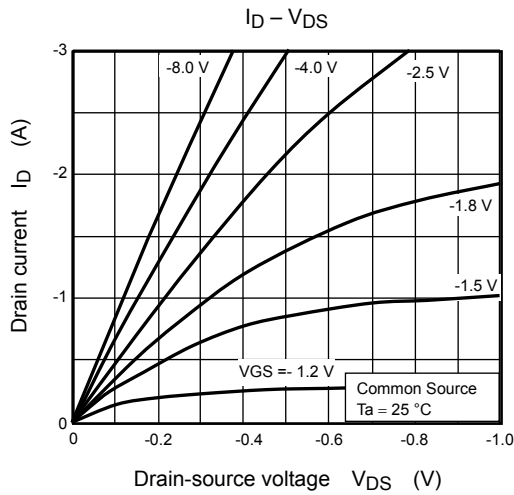
Q1 (N-ch MOSFET)



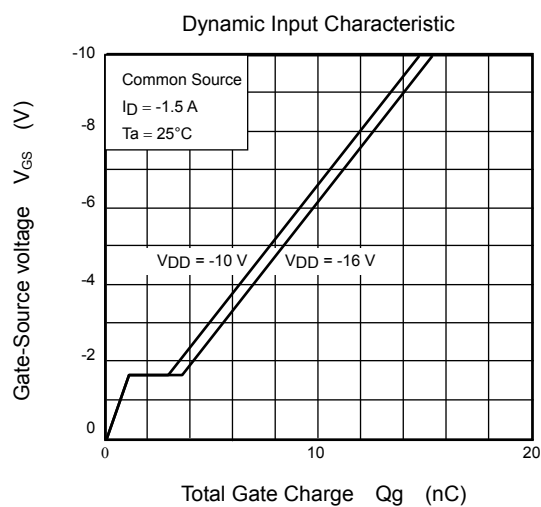
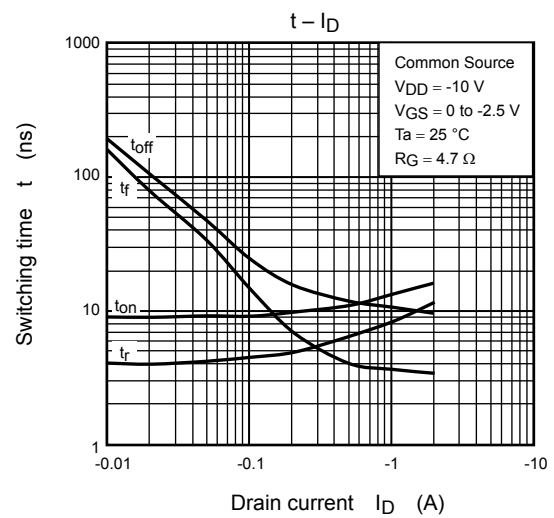
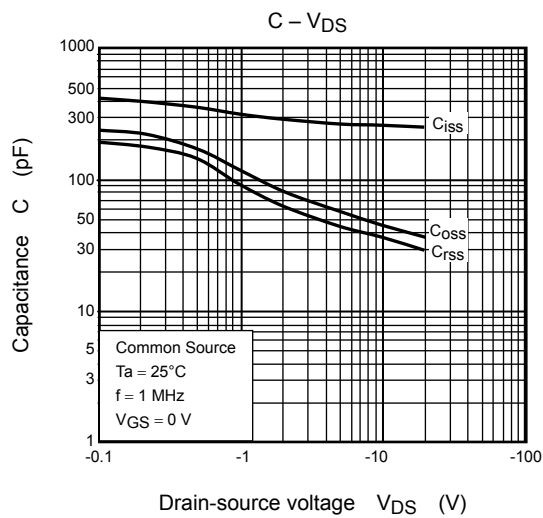
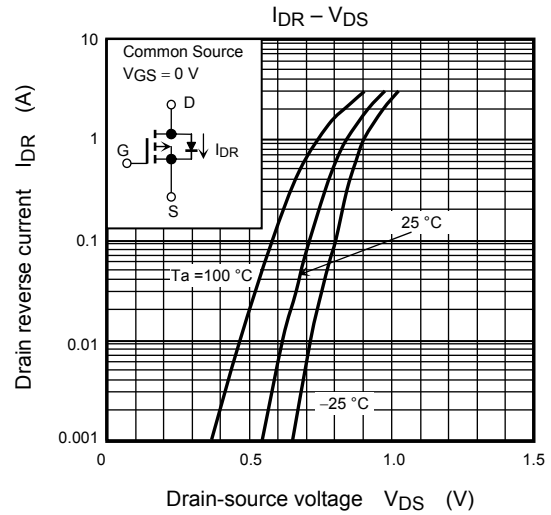
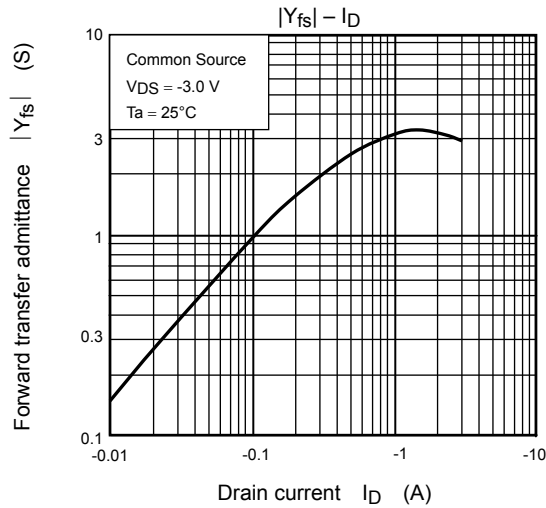
Q1 (N-ch MOSFET)



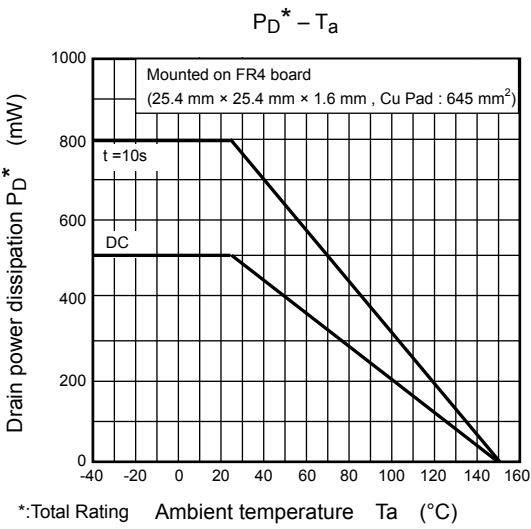
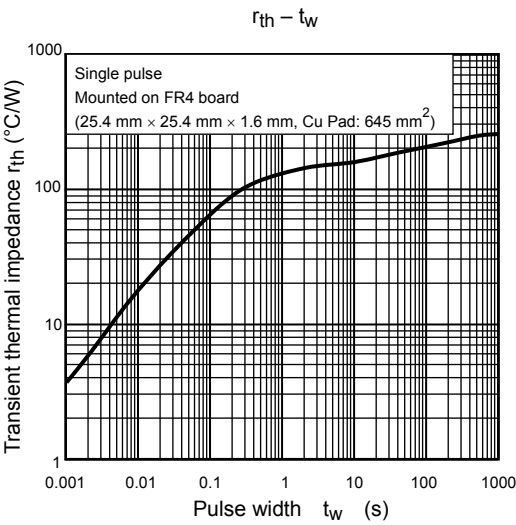
Q2 (P-ch MOSFET)



Q2 (P-ch MOSFET)



Q1,Q2 Common



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